## NSN 5962-01-228-9816

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 1.230 inches and 1.285 inches
Body Width:
Between 0.510 inches and 0.545 inches
Body Height:
Between 0.135 inches and 0.165 inches
Operating Tempurature Range:
-55.0 to 125.0 degrees celsius
Storage Tempurature Range:
-65.0 to 150.0 degrees celsius
Features Provided:
Hermetically sealed and bipolar and programmable and high performance and asynchronous and schottky
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0